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November 2015

FDPF190N15A N-Channel PowerTrench[®] MOSFET 150 V, 27.4 A, 19 mΩ

Features

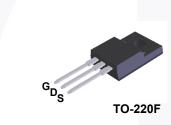
- $R_{DS(on)}$ = 14.7 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 27.4 A
- Low Gate Charge, Q_G = 31 nC (Typ.)
- Low C_{rss} (Typ. 56 pF)
- · Fast Switching Speed
- · Improved dv/dt Capability
- RoHS Compliant

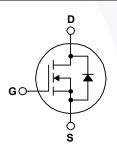
Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Consumer Appliances
- LED TV
- · Synchronous Rectification for ATX / Sever / Telecom PSU
- Uninterruptible Power Supply
- Micro Solar Inverter





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

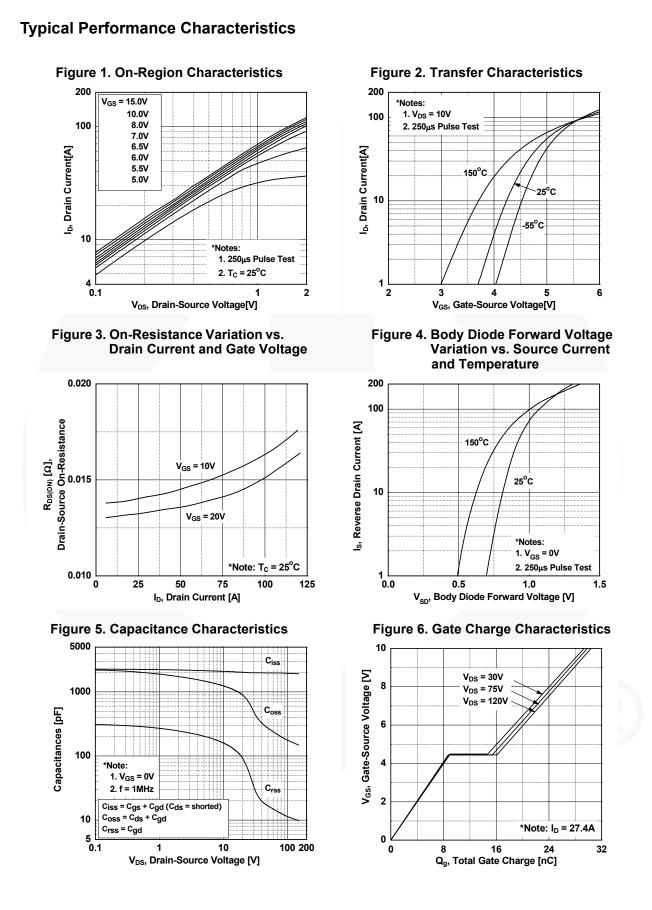
Symbol		FDPF190N15A	Unit V			
V _{DSS}	Drain to Source Voltage	150				
V _{GSS}	Cata ta Sauraa Valtaga	- DC	±20	v		
	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V	
ID	Drain Current	- Continuous (T _C = 25 ^o C)		27.4	•	
	Drain Current	- Continuous (T _C = 100 ^o C)		17.4	- A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	110	Α	
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	261	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3		(Note 3)	6.0	V/ns	
P _D	Dower Dissinction	(T _C = 25 ^o C)		33	W	
	Power Dissipation	- Derate Above 25°C		0.26	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

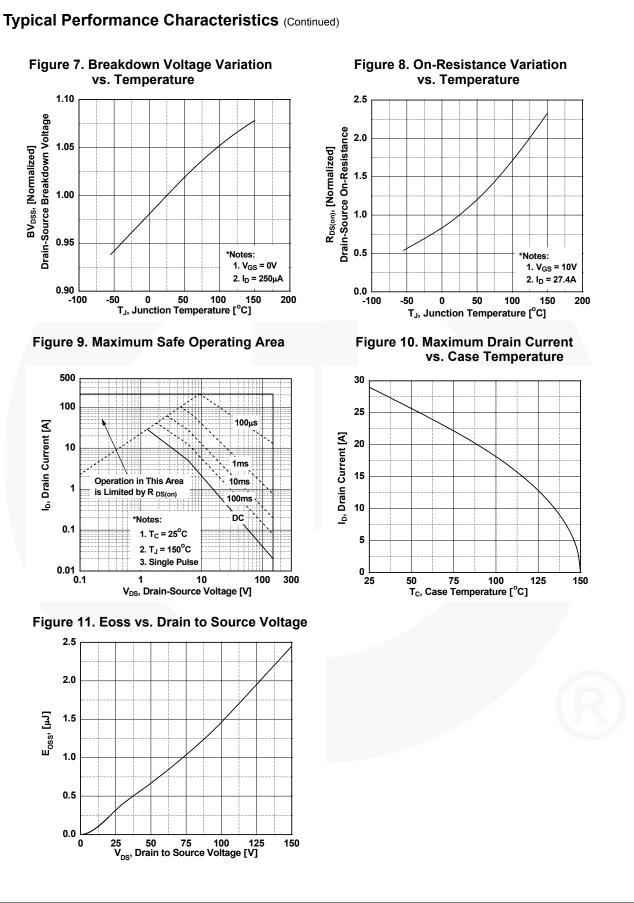
Thermal Characteristics

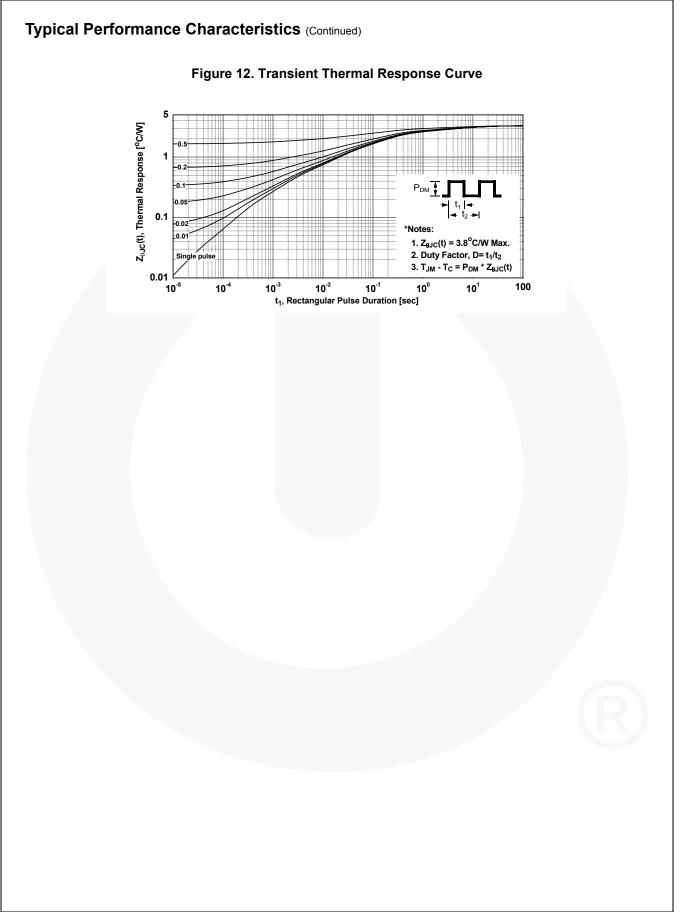
Symbol	Parameter	FDPF190N15A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	3.3	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W

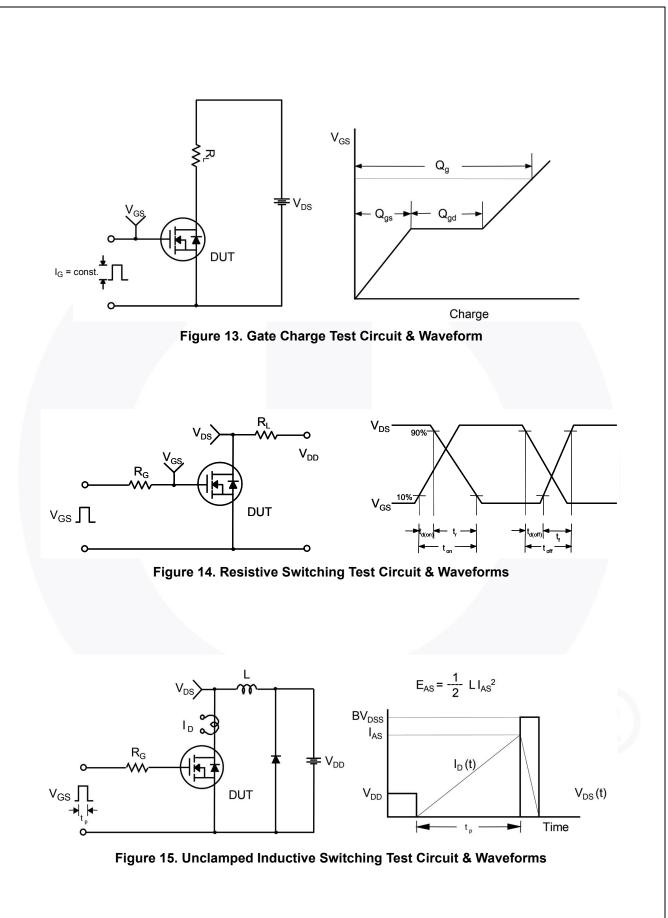
• • • •		Package	• •		ze Tape Width N/A		ı Qu	Quantity	
		TO-220F					50 units		
Electrica	I Chara	acteristics T _c = 25 ^c	^o C unless of	therwise noted.					
Symbol Parameter			Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristics	6							
BV _{DSS}	Drain to Source Breakdown Voltage		ae	I _D = 250 μA, V _{GS} = 0 V		150	-	-	V
ΔBV_{DSS}	Broakdown Voltago Tomporaturo								
$/\Delta T_J$	Coefficie	e 1		$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$		-	0.14	-	V/ºC
I _{DSS}	Zero Gate Voltage Drain Current			V _{DS} = 120 V, V _{GS} = 0 V		-	-	1	μA
200		Ŭ		V_{DS} = 120 V, T_{C} = 150°C		-	-	500	μΛ
I _{GSS}	Gate to Body Leakage Current		Y	V_{GS} = ±20 V, V_{DS} = 0 V		-	-	±100	nA
On Charac	teristics								
V _{GS(th)}	Gate Thr	reshold Voltage	,	V _{GS} = V _{DS} , I _D = 250 μA		2.0	-	4.0	V
R _{DS(on)}	Static Dr.	ain to Source On Resista		V _{GS} = 10 V, I _D = 27.4 A		-	14.7	19.0	mΩ
9 _{FS}	Forward	Transconductance		V _{DS} = 10 V, I _D = 27.4 A		-	64	-	S
Dynamic C	-								1
C _{iss}		pacitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		-	2020	2685	pF
C _{oss}		apacitance				-	700	930	pF
C _{rss}		Transfer Capacitance				-	56	85	pF
C _{oss(er)}		Related Output Capacitan	ce	V _{DS} = 75 V, V _{GS} = 0 V		-	252	-	pF
Q _{g(tot)}		e Charge at 10V	,	V _{DS} = 120 V, I _D = 27.4	А,	-	30	39	nC
Q _{gs}		Source Gate Charge	'	V _{GS} = 10 V (Note 4)		-	8.8	-	nC
Q _{gd}		Drain "Miller" Charge				-	7.3	-	nC
ESR	Equivale	nt Series Resistance (G-	S) ·	f = 1 MHz		-	1.5	-	Ω
	Charact	eristics							
Switching	Turn-On	Delay Time		$V_{DD} = 75 \text{ V}, \text{ I}_{D} = 27.4 \text{ A},$ $V_{GS} = 10 \text{ V}, \text{ R}_{G} = 4.7 \Omega$ (Note 4)		-	18	46	ns
	Turn-On	Rise Time				-	16	42	ns
t _{d(on)}							32	74	ns
t _{d(on)} t _r	Turn-Off	Delay Time					8	26	ns
Switching t _{d(on)} t _r t _{d(off)} t _f		Delay Time Fall Time			(Note 4)				
t _{d(on)} t _r t _{d(off)} t _f	Turn-Off	Fall Time			(Note 4)	7	I		
t _{d(on)} t _r t _{d(off)} t _f Drain-Sou	Turn-Off	Fall Time e Characteristics		Forward Current	(Note 4)	<u> </u>	-	27.4	A
t _{d(on)} t _r t _{d(off)} t _f Drain-Sou	Turn-Off rce Diod	Fall Time	urce Diode		(Note 4)	/	-	27.4 110	A
t _{d(on)} t _r t _{d(off)} t _f Drain-Sou I _S I _{SM}	Turn-Off rce Diod Maximum Maximum	Fall Time e Characteristics n Continuous Drain to So	urce Diode Diode Forw	ard Current	(Note 4)	/			-
t _{d(on)} t _r t _{d(off)} t _f Drain-Sou	Turn-Off rce Diod Maximum Maximum Drain to S	Fall Time e Characteristics n Continuous Drain to Sou n Pulsed Drain to Source	urce Diode Diode Forw Ditage			/	- - - 76	110	Α

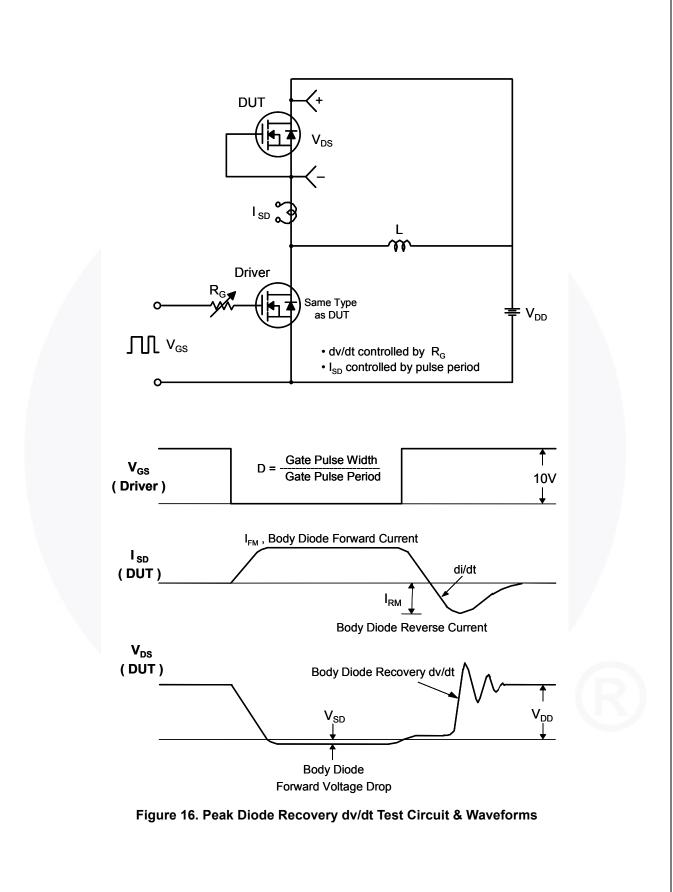
1. Repetitive rating: pulse-width limited by maximum junction temperature. 2. L = 0.33 mH, I_{AS} = 29 A, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 27.4 A, di/dt \leq 200 A/µs, V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature typical characteristics.

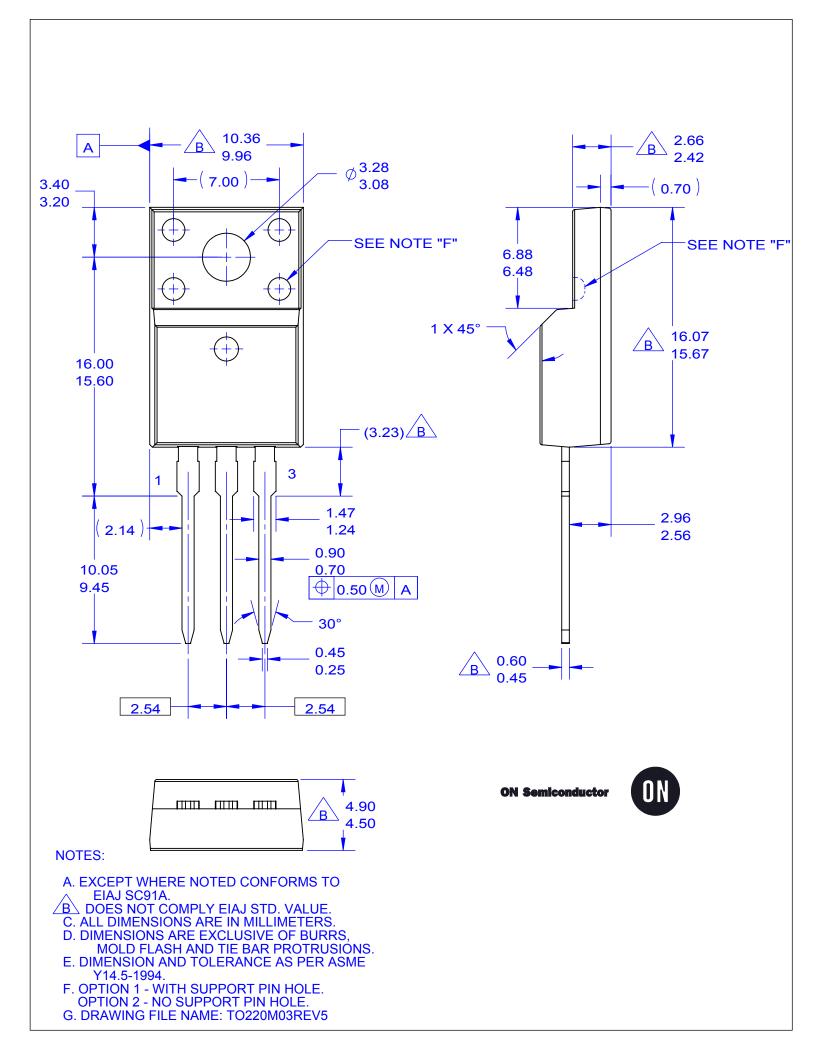












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